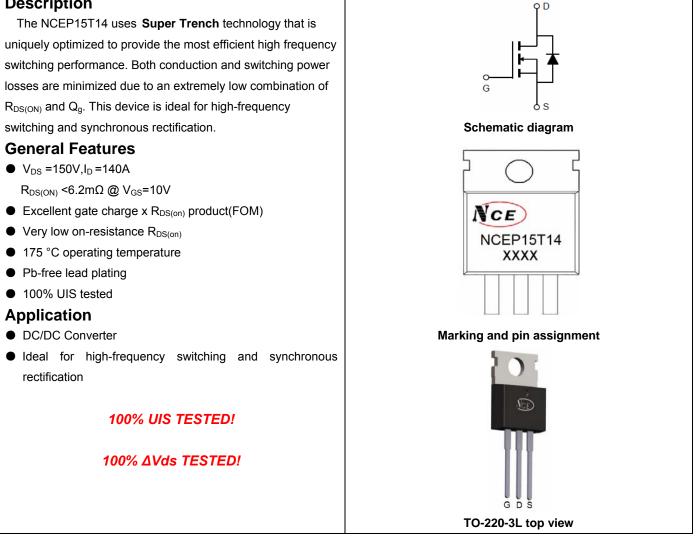


NCE N-Channel Super Trench Power MOSFET

Description



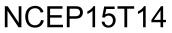
Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15T14	NCEP15T14	TO-220-3L	-	-	-

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	150	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	140	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	100	А
Pulsed Drain Current	I _{DM}	560	А
Maximum Power Dissipation	PD	320	W
Derating factor		2.1	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	1296	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C





Thermal Characteristic

	Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	0.47	°C/W
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Electrical Characteristics (T_C=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	i					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	150	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =150V, V_{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	i					
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250µA	2.0	3	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =70A	-	5.6	6.2	mΩ
Forward Transconductance	g fs	V _{DS} =10V,I _D =70A	70	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	5900	-	PF
Output Capacitance	C _{oss}	V_{DS} =75V, V_{GS} =0V,	-	690	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	7	-	PF
Switching Characteristics (Note 4)	i					
Turn-on Delay Time	t _{d(on)}		-	26	-	nS
Turn-on Rise Time	tr	V _{DD} =75V,I _D =70A	-	36	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =4.7 Ω	-	47	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg		-	80		nC
Gate-Source Charge	Q _{gs}	V_{DS} =75V,I _D =70A,	-	32		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	13		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _F = I _S	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	140	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-	140		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	498		nC

Notes:

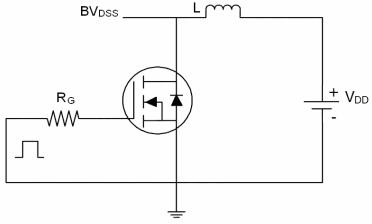
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25\Omega



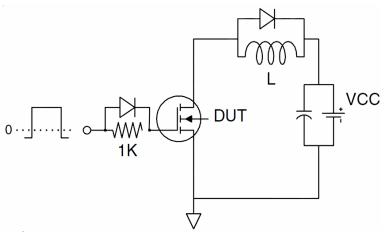
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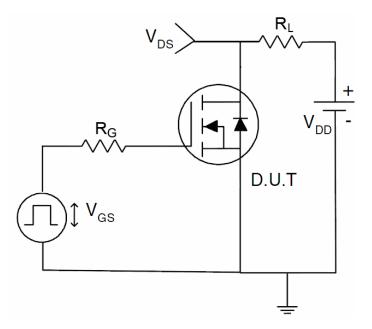
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

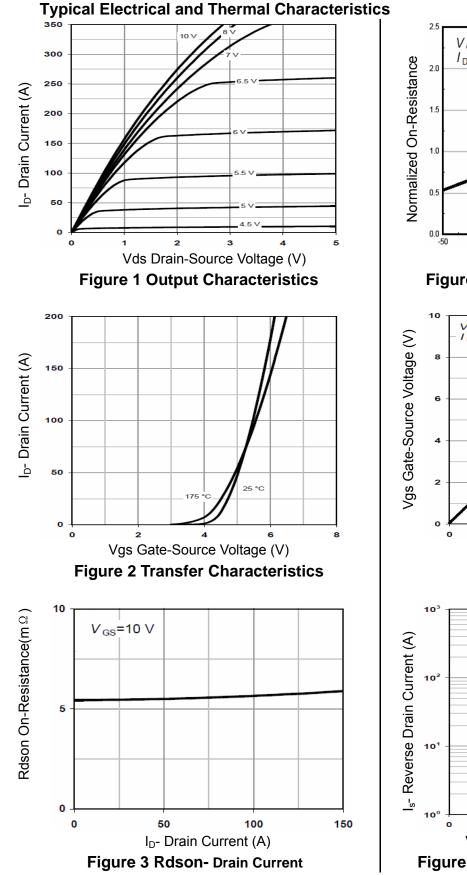


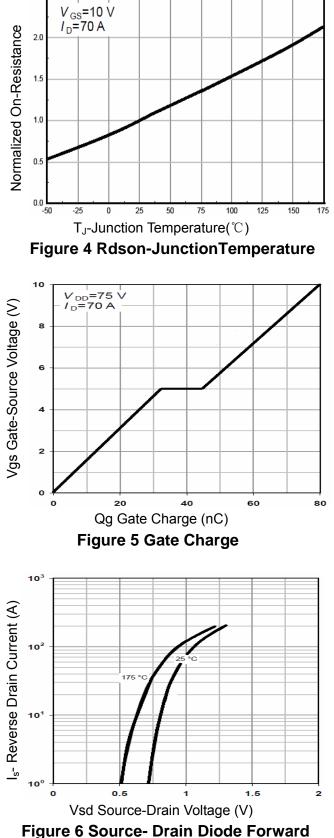
3) Switch Time Test Circuit







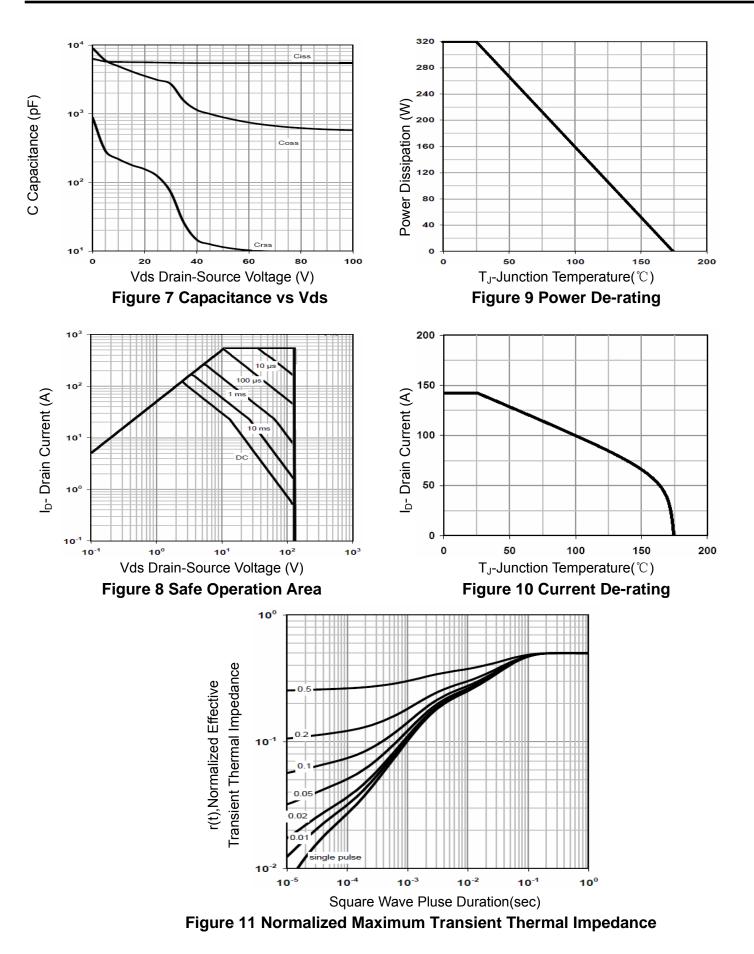






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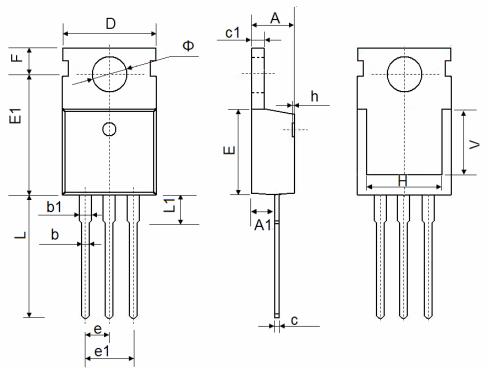




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TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Φ	3.400	3.800	0.134	0.150	





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